

## isc N-Channel MOSFET Transistor

## **FQP13N10**

### • FEATURES

- · Drain Source Voltage-
  - : V<sub>DSS</sub>= 100V(Min)
- Static Drain-Source On-Resistance
  - :  $R_{DS(on)}$  ≤180m  $\Omega$  @ $V_{GS}$  = 10V
- · Fast Switching
- · 100% avalanche tested
- Minimum Lot-to-Lot variations for robust device performance and reliable operation

### APPLICATIONS

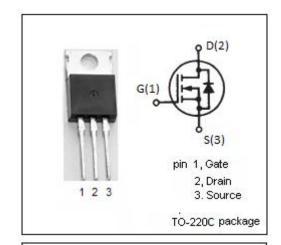


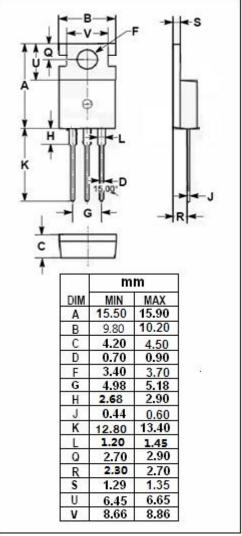
# • ABSOLUTE MAXIMUM RATINGS(Ta=25°C)

SYMBOL	PARAMETER	VALUE	UNIT	
V <sub>DSS</sub>	Drain-Source Voltage	100	V	
V <sub>GSS</sub>	Gate-Source Voltage	±25	5 V	
I <sub>D</sub>	Drain Current-Continuous@T <sub>c</sub> =25℃ T <sub>c</sub> =100℃	12.8 9.05	А	
I <sub>DM</sub>	Drain Current-Single Pulsed	51.2	А	
P <sub>D</sub>	Total Dissipation	65	W	
T <sub>j</sub>	Operating Junction Temperature -55~175		°C	
T <sub>stg</sub>	Storage Temperature	-55~175	°C	

#### • THERMAL CHARACTERISTICS

SYMBOL	PARAMETER	MAX	UNIT
Rth(ch-c)	Channel-to-case thermal resistance	2.31	°C/W





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### **ELECTRICAL CHARACTERISTICS**

T<sub>C</sub>=25℃ unless otherwise specified

SYMBOL	PARAMETER	CONDITIONS	MIN	TYP	MAX	UNIT
BV <sub>DSS</sub>	Drain-Source Breakdown Voltage	V <sub>GS</sub> =0V; I <sub>D</sub> = 250uA	100			V
V <sub>GS(th)</sub>	Gate Threshold Voltage	V <sub>DS</sub> =V <sub>GS</sub> ; I <sub>D</sub> =250uA	2		4	V
R <sub>DS(on)</sub>	Drain-Source On-Resistance	V <sub>GS</sub> = 10V; I <sub>D</sub> =6.4A			180	mΩ
I <sub>GSS</sub>	Gate-Source Leakage Current	V <sub>GS</sub> = ±25V;V <sub>DS</sub> = 0V			±100	nA
I <sub>DSS</sub>	Drain-Source Leakage Current	V <sub>DS</sub> = 100V; V <sub>GS</sub> = 0V; V <sub>DS</sub> = 80V; V <sub>GS</sub> = 0V;T <sub>C</sub> = 150°C			1 10	μА
V <sub>SDF</sub>	Diode forward voltage	I <sub>SD</sub> =12.8A, V <sub>GS</sub> = 0 V			1.5	V

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